

Dandan Sang

List of Publications by Year in descending order

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| # | ARTICLE | IF | CITATIONS |
|----|--|-----|-----------|
| 1 | A Review on the Properties and Applications of WO ₃ Nanostructure-Based Optical and Electronic Devices. <i>Nanomaterials</i> , 2021, 11, 2136. | 4.1 | 63 |
| 2 | Fabrication and high temperature electronic behaviors of n-WO ₃ nanorods/p-diamond heterojunction. <i>Applied Physics Letters</i> , 2017, 110, 052106. | 3.3 | 21 |
| 3 | Ionic transport and dielectric properties in NaNbO ₃ under high pressure. <i>Applied Physics Letters</i> , 2017, 111, . | 3.3 | 14 |
| 4 | Improved electrical transport properties of an n-ZnO nanowire/p-diamond heterojunction. <i>RSC Advances</i> , 2018, 8, 28804-28809. | 3.6 | 14 |
| 5 | Review on the Properties of Boron-Doped Diamond and One-Dimensional-Metal-Oxide Based P-N Heterojunction. <i>Molecules</i> , 2021, 26, 71. | 3.8 | 13 |
| 6 | Ionic conduction in sodium azide under high pressure: Experimental and theoretical approaches. <i>Applied Physics Letters</i> , 2018, 112, 173903. | 3.3 | 12 |
| 7 | Negative Differential Resistance of n-ZnO Nanorods/p-degenerated Diamond Heterojunction at High Temperatures. <i>Frontiers in Chemistry</i> , 2020, 8, 531. | 3.6 | 12 |
| 8 | Excellent optoelectronic applications and electrical transport behavior of the n-WO ₃ nanostructures/p-diamond heterojunction: a new perspective. <i>Nanotechnology</i> , 2021, 32, 332501. | 2.6 | 8 |
| 9 | Dielectric properties and the role of grain boundaries in polycrystalline tetracene at high pressures. <i>CrystEngComm</i> , 2019, 21, 4507-4512. | 2.6 | 6 |
| 10 | Enhanced Photoluminescence and Electrical Properties of n-Al-Doped ZnO Nanorods/p-B-Doped Diamond Heterojunction. <i>International Journal of Molecular Sciences</i> , 2022, 23, 3831. | 4.1 | 6 |
| 11 | Conduction transition and electronic conductivity enhancement of cesium azide by pressure-directed grain boundary engineering. <i>Journal of Materials Chemistry C</i> , 2021, 9, 4764-4770. | 5.5 | 3 |
| 12 | Improved Dielectric Properties and Grain Boundary Effect of Phenanthrene Under High Pressure. <i>Frontiers in Physics</i> , 2021, 9, . | 2.1 | 2 |
| 13 | Pressure-induced transition from pure electronic to mixed ionic-electronic conduction in strontium hydride. <i>Applied Physics Letters</i> , 2022, 120, 073904. | 3.3 | 2 |